

1. General description

Silicon Carbide Schottky diode in a ITO220-2L plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- New 6th Generation Technology
- Low Forward Voltage Drop
- Low Reverse Leakage Current
- High Forward Surge Capability I_{FSM}
- Reduced Losses in Associated MOSFET
- Reduced EMI
- Reduced Cooling Requirements
- RoHS Compliant
- Insulated package rated at 2500V RMS

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

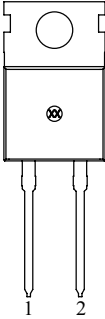
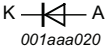
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute maximum rating							
V_{RRM}	repetitive peak reverse voltage			650			V
I_F	continuous forward current	$T_{mb} \leq 146 \text{ }^\circ\text{C}$, DC; Fig. 2		6			A
T_j	junction temperature			-55 to 175			$^\circ\text{C}$
Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V_F	forward voltage	$I_F = 6 \text{ A}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 5		-	1.26	1.40	V
		$I_F = 6 \text{ A}$; $T_j = 150 \text{ }^\circ\text{C}$; Fig. 5		-	1.35	1.55	V
Dynamic characteristics							
Q_r	recovered charge	$I_F = 6 \text{ A}$; $di_F/dt = 500 \text{ A}/\mu\text{s}$; $V_R = 400 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; Fig. 7		-	13.5	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	n.c.	mounting base; isolated		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC6D06650Y	IITO220-2L	WNSC6D06650Y6Q	Tube	50	IITO220P-2L	13-Mar-2023

7. Marking

Table 4. Marking codes

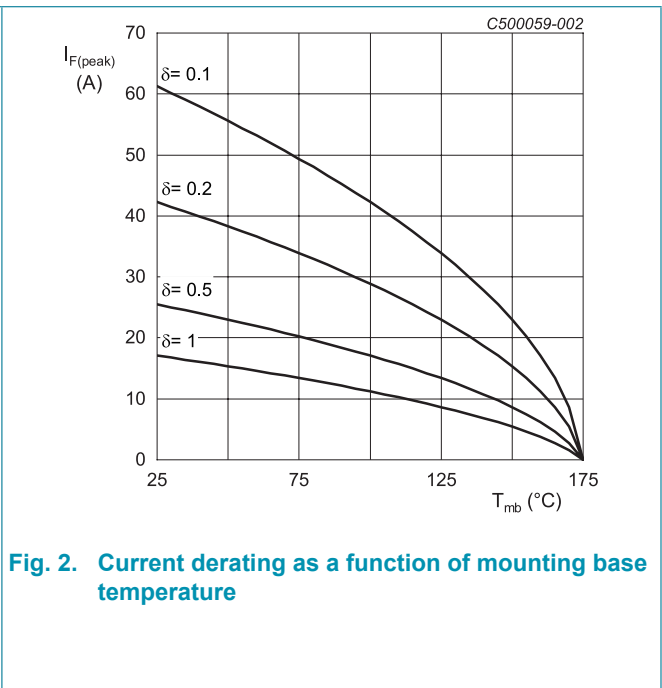
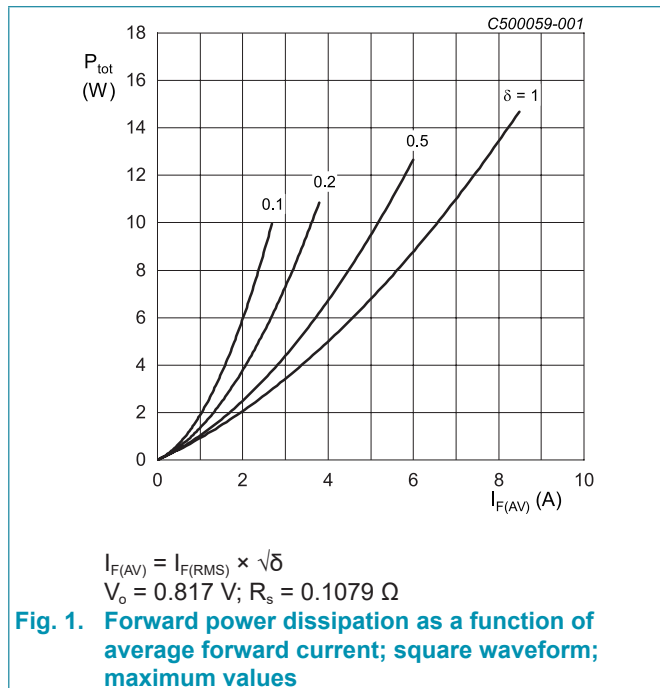
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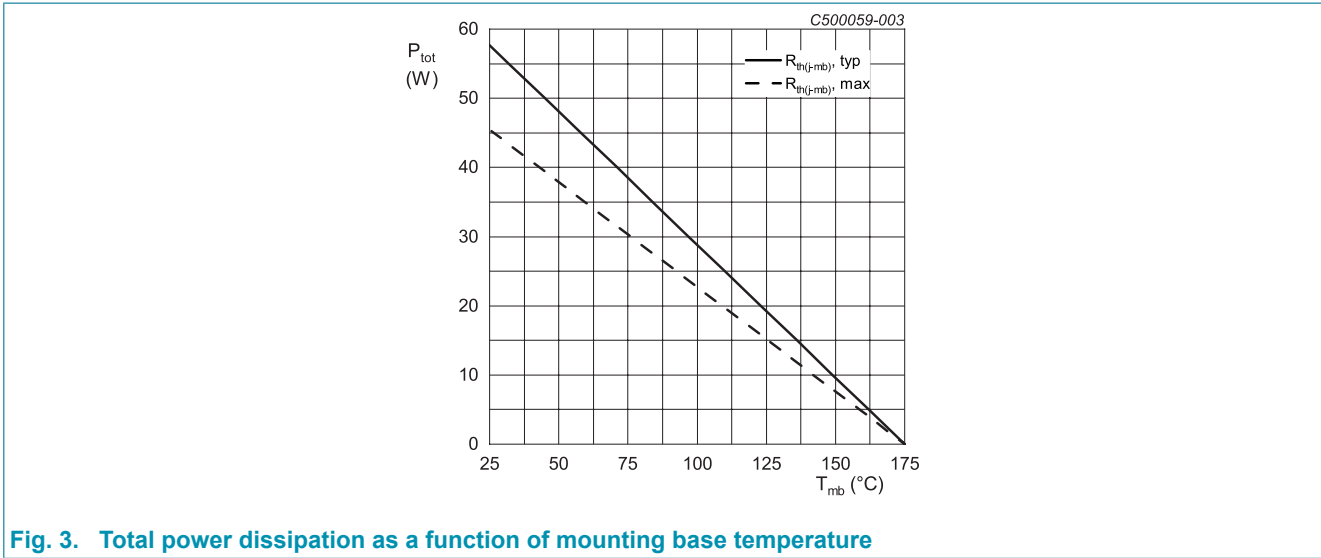
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
I_F	continuous forward current	$T_{mb} \leq 146\text{ }^\circ\text{C}$; DC; Fig. 2		6	A
		$T_{mb} \leq 125\text{ }^\circ\text{C}$; DC; Fig. 2		8	A
		$T_{mb} \leq 25\text{ }^\circ\text{C}$; DC; Fig. 2		17	A
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25\text{ }\mu\text{s}$; $T_{mb} \leq 125\text{ }^\circ\text{C}$; square-wave pulse		13	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; sine-wave pulse		50	A
		$t_p = 10\text{ }\mu\text{s}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; square-wave pulse		610	A
I^2t	I^2t for fusing	$t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^\circ\text{C}$; sine-wave pulse		12.5	A^2s
T_{stg}	storage temperature			-55 to 175	$^\circ\text{C}$
T_j	junction temperature			-55 to 175	$^\circ\text{C}$





9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 4		-	2.6	3.3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

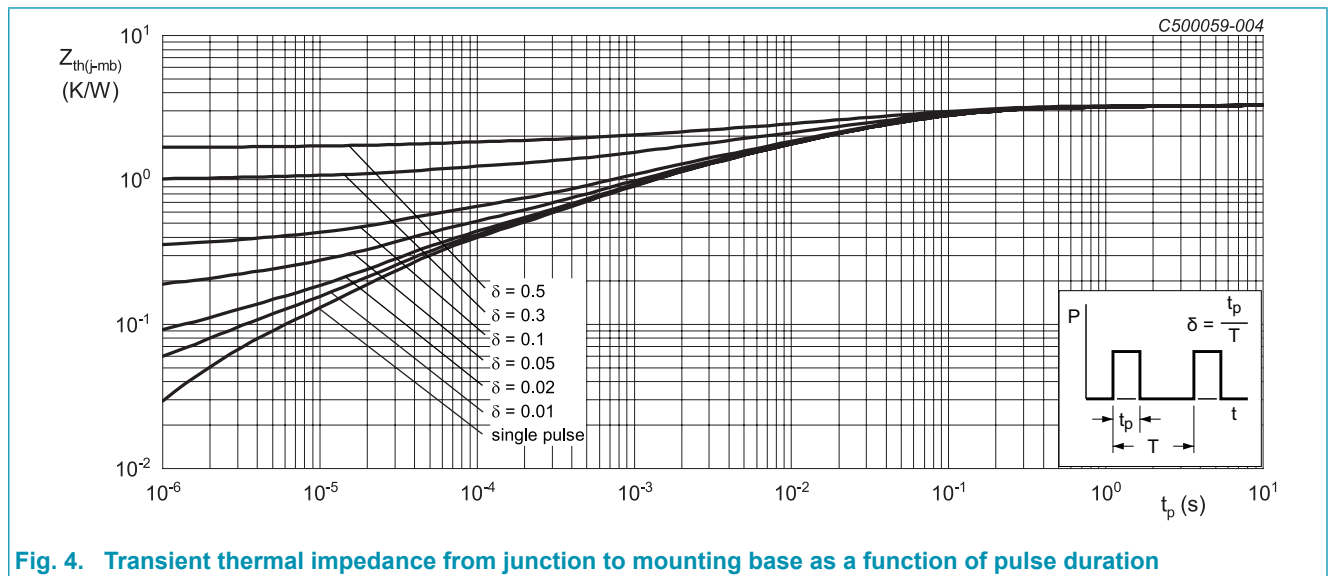


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Isolation characteristics

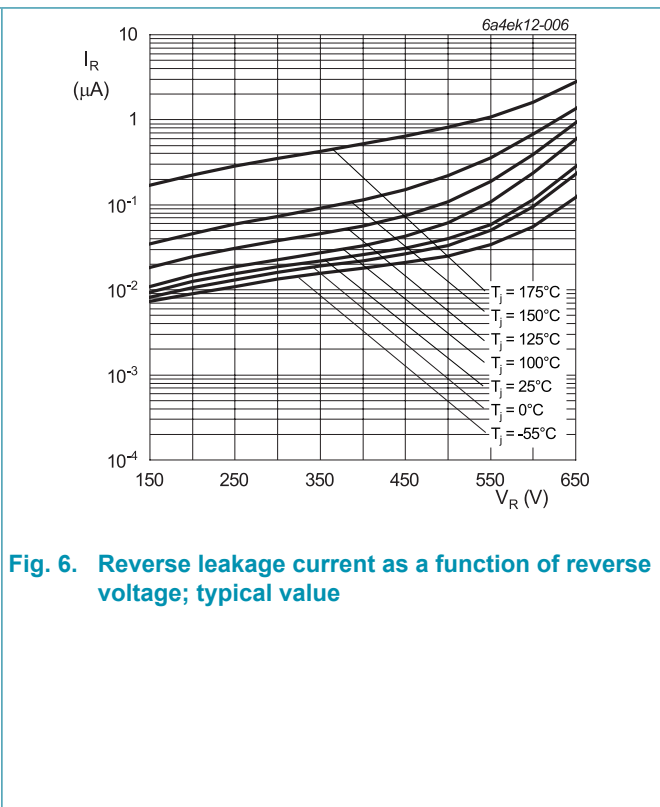
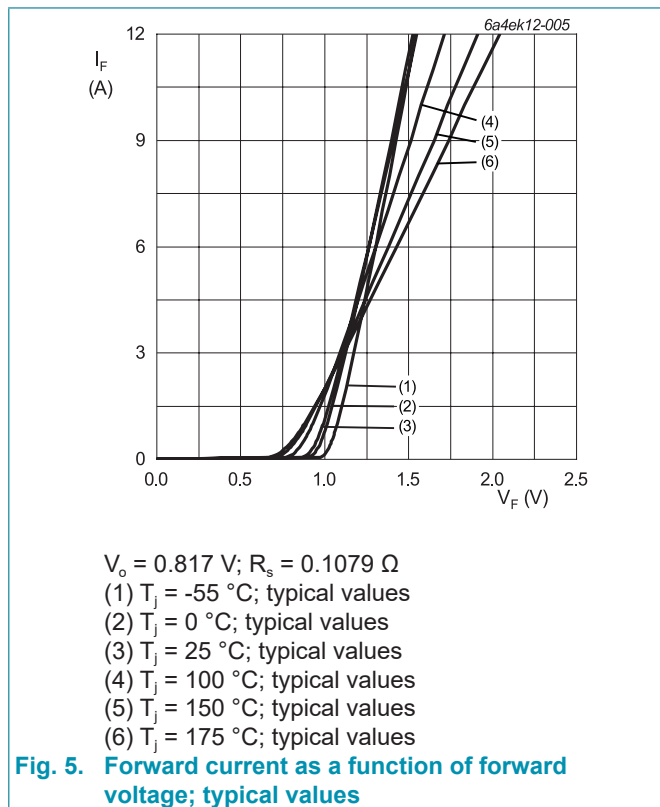
Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; $50\text{ Hz} \leq f \leq 60\text{ Hz}$; $T_h = 25\text{ }^\circ\text{C}$; $RH \leq 65\%$		-	-	2500	V

11. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V_F	forward voltage	$I_F = 6\text{ A}; T_j = 25\text{ °C}; \text{Fig. 5}$		-	1.26	1.40	V
		$I_F = 6\text{ A}; T_j = 150\text{ °C}; \text{Fig. 5}$		-	1.35	1.55	V
		$I_F = 6\text{ A}; T_j = 175\text{ °C}; \text{Fig. 5}$		-	1.40	1.60	V
I_R	reverse current	$V_R = 650\text{ V}; T_j = 25\text{ °C}; \text{Fig. 6}$		-	0.6	30	μA
		$V_R = 650\text{ V}; T_j = 175\text{ °C}; \text{Fig. 6}$		-	9	120	μA
Dynamic characteristics							
Q_r	recovered charge	$I_F = 6\text{ A}; V_R = 400\text{ V}; dI_F/dt = 500\text{ A}/\mu\text{s}; T_j = 25\text{ °C}; \text{Fig. 7}$		-	13.5	-	nC
C_d	diode capacitance	$f = 1\text{ MHz}; V_R = 1\text{ V}; T_j = 25\text{ °C}$		-	313	-	pF
		$f = 1\text{ MHz}; V_R = 300\text{ V}; T_j = 25\text{ °C}$		-	35	-	pF
		$f = 1\text{ MHz}; V_R = 600\text{ V}; T_j = 25\text{ °C}$		-	32	-	pF
E_{as}	non-repetitive avalanche energy	$I_R = 4\text{ A}; T_{j(\text{init})} = 25\text{ °C}; L = 5\text{ mH}$		40	-	-	mJ



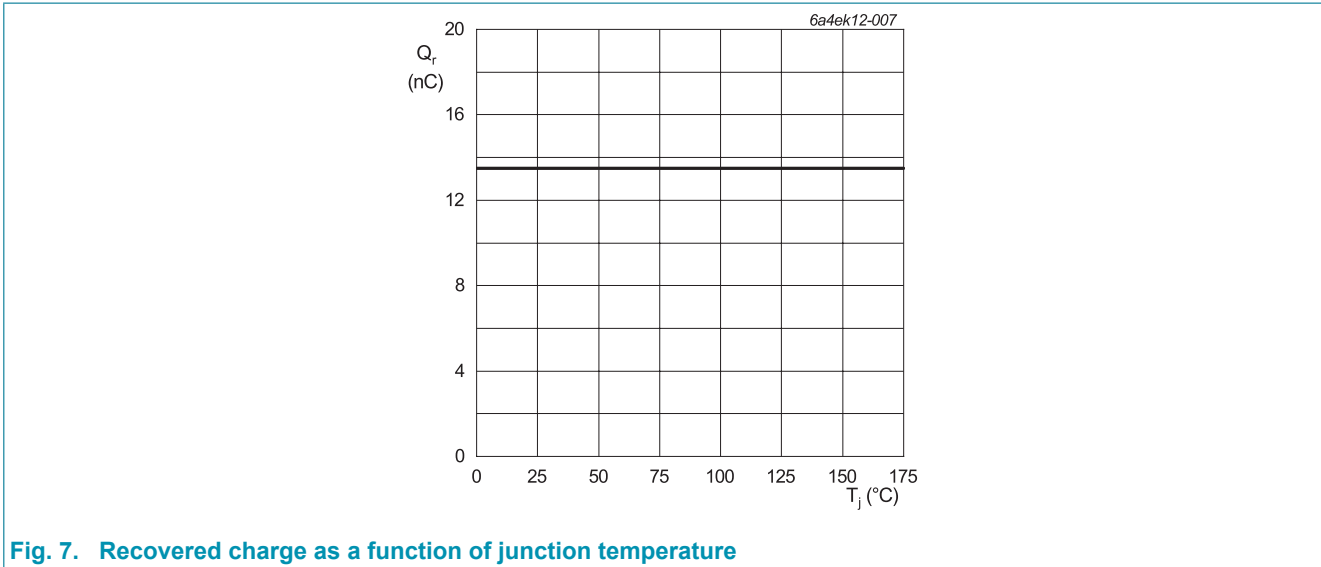
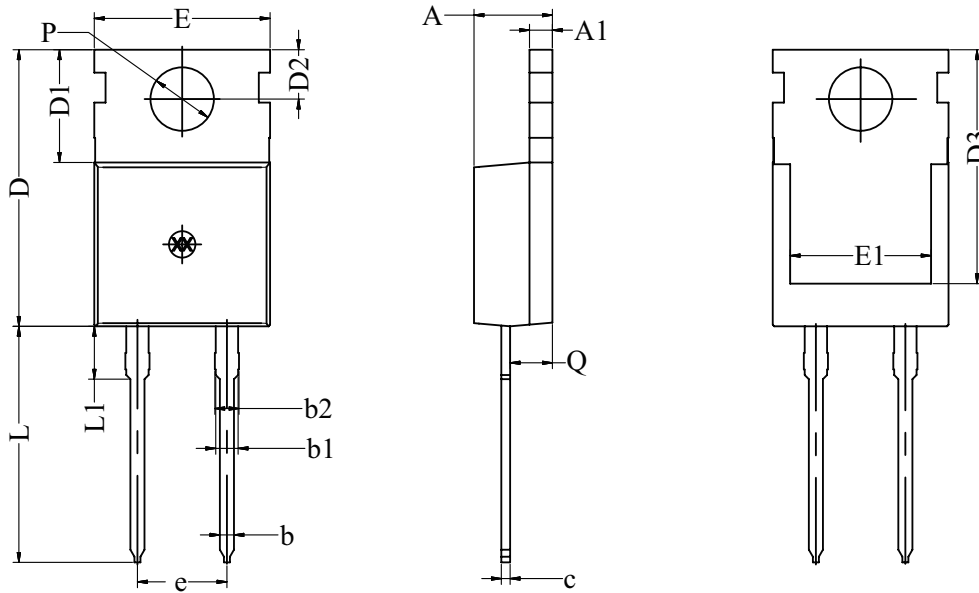


Fig. 7. Recovered charge as a function of junction temperature

12. Package outline

Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2 leads TO-220 ITO220-2L



Dim	All Dimensions in Millimeters		
	Min	Typ	Max
A	4.30	4.45	4.70
A1	1.25	1.30	1.40
b	0.60	0.80	0.90
b1	1.10	1.27	1.40
b2	1.32	1.37	1.72
c	0.40	0.50	0.60
D	15.20	15.70	16.00
D1	6.20	6.40	6.60
D2	2.70	2.80	3.00
D3	12.98	13.28	13.58
E	9.70	10.00	10.30
E1	7.50	8.00	8.50
e	5.08(BSC)		
L	12.80	13.40	14.00
L1	2.80	3.00	3.20
P	3.50	3.60	3.70
Q	2.20	2.40	2.60

13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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